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Unit: mm

TOSHIBA Power Transistor Module Silicon PNP Triple Diffused Type (Four Darlington Power Transistors in One)

MP4009

High Power Switching Applications Hammer Drive, Pulse Motor Drive Inductive Load Switching

- Small package by full molding (SIP 10 pins) ٠
- High collector power dissipation (4-device operation) $: P_T = 4 W (Ta = 25^{\circ}C)$
- High collector current: $I_{C(DC)} = -5 A(max)$ •
- High DC current gain: $h_{FE} = 1000$ (min) ($V_{CE} = -3 \text{ V}$, $I_C = -3 \text{ A}$) •
- Complementary to MP4003 •

Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V _{CBO}	-100	V	
Collector-emitter voltage		V _{CEO}	-100	V	
Emitter-base voltage		V _{EBO}	-5	V	
Collector current	DC	Ι _C	-5	A	
	Pulse	I _{CP}	-8		
Continuous base current		Ι _Β	-0.1	А	
Collector power dissipation (1 device operation)		Pc	2.0	W	
Collector power dissipation (4 devices operation)		PT	4.0	W	
Junction temperature		Тj	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	



Weight: 2.1 g (typ.)

Array Configuration



R1 ≈ 5 kΩ, R2 ≈ 120 Ω





Thermal Characteristics

Characteristics	Symbol	Max	Unit	
Thermal resistance from junction to ambient	ΣR _{th (j-a)}	31.3	°C/W	
4-device operation, Ta = 25°C)				
Maximum lead temperature for soldering purposes	TL	260	°C	
(3.2 mm from case for 10 s)				

Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit	
Collector cut-off current		I _{CBO}	V _{CB} = -100 V, I _E = 0 A	—	—	-10	μA	
Collector cut-off current		I _{CEO}	V _{CE} = -100 V, I _B = 0 A	—	—	-10	μA	
Emitter cut-off current		I _{EBO}	$V_{EB} = -5 V, I_C = 0 A$	-0.3	_	-2.0	mA	
Collector-base breakdown voltage		V (BR) CBO	I _C = -1 mA, I _E = 0 A	-100	_	_	V	
Collector-emitter breakdown voltage		V (BR) CEO	I _C = -30 mA, I _B = 0 A	-100	_	_	V	
DC current gain		h _{FE (1)}	$V_{CE} = -3 V, I_C = -0.5 A$	1000	_	_	_	
		h _{FE (2)}	$V_{CE} = -3 V, I_C = -3 A$	1000	_	_		
Saturation voltage	Collector-emitter	V _{CE (sat)}	I _C = -3 A, I _B = -12 mA	_	_	-2.0	v	
	Base-emitter	V _{BE (sat)}	I _C = -3 A, I _B = -12 mA	_	_	-2.5		
Transition frequency		fT	$V_{CE} = -3 V, I_C = -0.5 A$	3	_	_	MHz	
Collector output capacitance		C _{ob}	V _{CB} = 50 V, I _E = 0 A, f = 1MHz	_	40	_	pF	
Switching time	Turn-on time	t _{on}		_	0.5	_		
	Storage time	t _{stg}		_	3.0	_	μs	
	Fall time	t _f	20 µs −I _{B1} = I _{B2} = 12 mA, duty cycle ≤ 1%	_	2.0	_		

Marking



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